



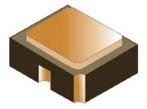
Schottky Barrier Diode Ceramic Surface Mount

Qualified per MIL-PRF-19500/444

<u>Qualified Levels:</u> JAN, JANTX, JANTXV and JANS

DESCRIPTION

This 1N5711UB and 1N5712UB Schottky barrier diode is ceramic encased and offers military grade qualifications for high-reliability applications. Unidirectional as well as doubler, common anode and common cathode polarities are available.



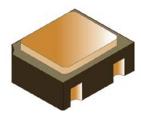
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FEATURES

- Surface mount equivalent of JEDEC registered 1N5711, 1N5712 numbers.
- JAN, JANTX, JANTXV and commercial qualifications also available per MIL-PRF-19500/444 on "1N" numbers only.

(See Part Nomenclature for all available options).

RoHS compliant by design.



UB Package

APPLICATIONS / BENEFITS

- Low reverse leakage characteristics.
- Low-profile ceramic surface mount package (see package illustration).
- ESD sensitive to Class 1.

Also available in:

DO-35 package (axial-leaded)

1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1



(surface mount) 1N5711UR-1, 1N5712UR-1, 1N6857UR-1, and 1N6858UR-1

MAXIMUM RATINGS @ 25 °C unless otherwise stated

Parameters/Test Conditions		Symbol	Value	Unit
Junction and Storage Temperature		T_{J} and T_{STG}	-65 to +150	٥C
Thermal Resistance, Junction-to-Solder Pad	$R_{\Theta JSP}$	100	°C/W	
Average Rectified Output Current:				
	1N5711UB ⁽¹⁾	Io	33	mA
	1N5712UB ⁽²⁾		75	
Solder Temperature @ 10 s			260	°C

NOTES: 1. At T_{EC} and T_{SP} = +140 °C, derate I_O to 0 at +150 °C.

2. At T_{EC} and T_{SP} = +130 °C, derate I_O to 0 at +150 °C.

MSC - Lawrence

6 Lake Street, Lawrence, MA 01841 Tel: 1-800-446-1158 or (978) 620-2600 Fax: (978) 689-0803

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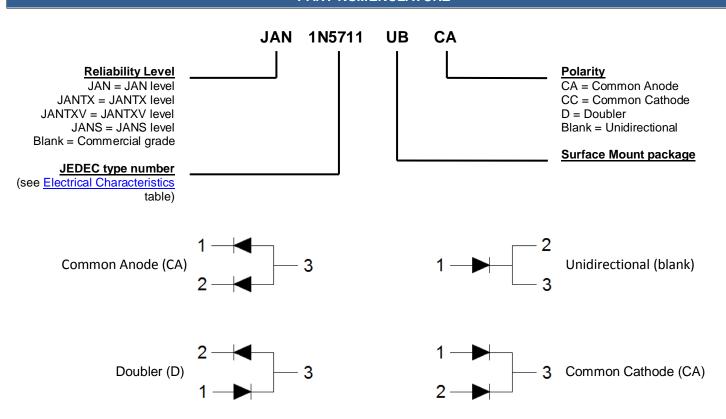
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MECHANICAL and PACKAGING

- CASE: Ceramic.
- TERMINALS: Gold plating over nickel under plate.
- MARKING: Part number, date code, manufacturer's ID.
- TAPE & REEL option: Standard per EIA-418D. Consult factory for quantities.
- WEIGHT: Approximately 0.04 grams.
- See Package Dimensions on last page.

PART NOMENCLATURE



	SYMBOLS & DEFINITIONS						
Symbol	Definition						
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.						
f	frequency						
I_R	Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage V _R .						
Io	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.						
t _{rr}	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.						
$V_{(BR)}$	Breakdown Voltage: A voltage in the breakdown region.						
V _F	Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current.						
V _R	Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region.						
V _{RWM}	Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV.						



ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise noted

TYPE NUMBER	MINIMUM MAXIMUM BREAKDOWN FORWARD VOLTAGE VOLTAGE		MAXIMUM WORKING FORWARD PEAK VOLTAGE REVERSE VOLTAGE		MAXIMUM REVERSE LEAKAGE CURRENT		MAXIMUM CAPACITANCE @ V _R = 0 VOLTS f = 1.0 MHz	
	V _(BR) @ 10 μA	V _F @ 1 mA	V _F @ I _F	V _{RWM}	I _R @ V _R		Ст	
	Volts	Volts	V @ mA	V (pk)	nA	Volts	pF	
1N5711UB	70	0.41	1.0 @ 15	50	200	50	2.0	
1N5712UB	20	0.41	1.0 @ 35	16	150	16	2.0	

NOTE:

1. Effective minority carrier lifetime (τ) is 100 pico seconds.



GRAPHS

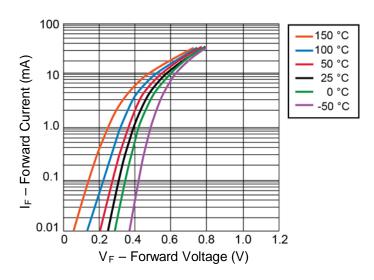


FIGURE 1

I-V Curve showing typical Forward Voltage Variation
Temperature for the 1N5712 Schottky Diodes

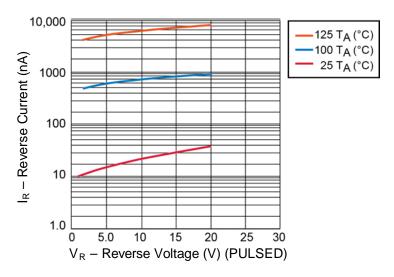


FIGURE 2

1N5712 Typical variation of Reverse

Current (I_R) vs Reverse Voltage (V_R) at Various Temperatures



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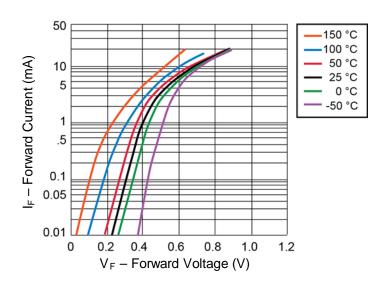


FIGURE 3

I – V curve showing typical Forward Voltage Variation
With Temperature Schottky Diode 1N5711

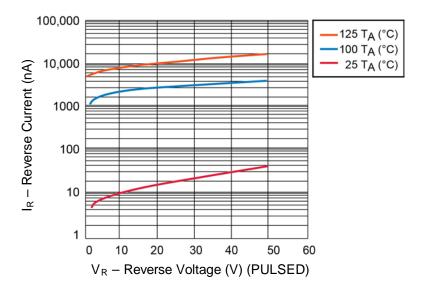


FIGURE 4

1N5711 Typical Variation of Reverse Current (I_R) vs Reverse Voltage (V_R)

at Various Temperatures



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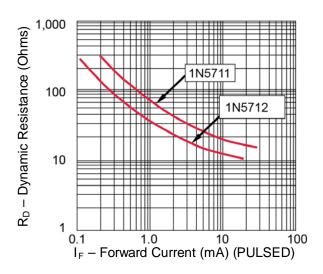
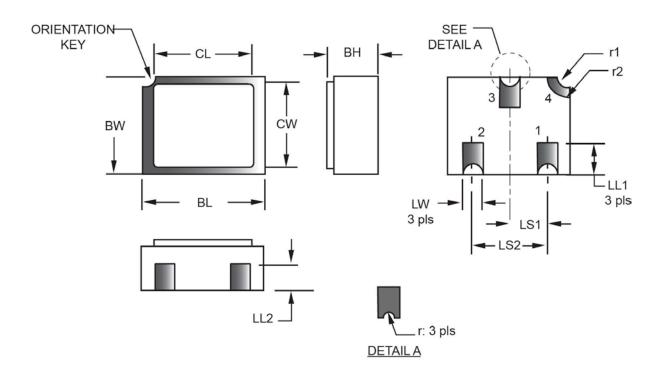


FIGURE 5

Typical Dynamic Resistance (R_D) vs Forward Current (I_F)



PACKAGE DIMENSIONS



Symbol	Dimensions					Dimensions					
	inch		millimeters		Note	Symbol	inch		millimeters		Note
	Min	Max	Min	Max			Min	Max	Min	Max	1
ВН	0.046	0.056	1.17	1.42		LS1	.035	.039	0.89	0.99	
BL	0.115	0.128	2.92	3.25		LS2	.071	.079	1.80	2.01	
BW	0.085	0.108	2.16	2.74		LW	.016	.024	0.41	0.61	
CL	-	0.128	-	3.25		r	-	.008	-	0.20	
CW	-	0.108	-	2.74		r1	-	.012	-	0.31	
LL1	0.022	0.038	0.56	0.97		r2	-	.022	-	.056	
LL2	0.017	0.035	0.43	0.89							

NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Ceramic package only.
- 3. Hatched areas on package denote metallized areas.
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

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JANTXN5711UBCC JANTXN5711UBD JANS1N5711UB/TR JANTXN5711UB/TR 1N5711UB/TR

1N5711UBCA/TR 1N5711UBD/TR 1N5712UB/TR 1N5712UBCA/TR 1N5712UBD/TR JANS1N5712UBD/TR

JANS1N5711UBD/TR LST7765 LST7764